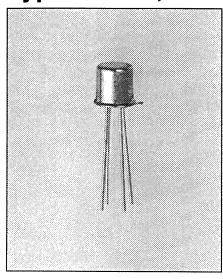
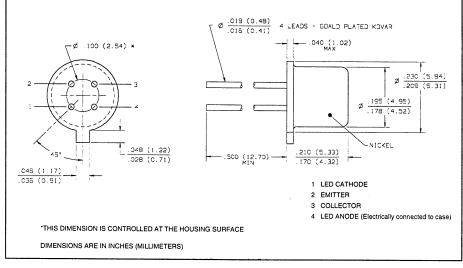


Optically Coupled Isolator Type 3C92C, 3C92CHR, 3C92CTX, 3C92CTXV





Features

- TO-72 hermetic package
- 1 kVDC electrical isolation
- High current transfer ratio

Description

The 3C92C is an optically coupled isolator consisting of an infrared emitting diode and an NPN silicon phototransistor mounted in a hermetically sealed TO-72 package.

Typical screening and lot acceptance tests are provided on page 13-4.

The 3C92CHR device has been 100% screened as a TXV device although Group B and C testing is not performed.

Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

| Input to Output Isolation Voltage |
|---|
| Operating Temperature Range55° C to +125° C |
| Storage Temperature Range65° C to +150° C |
| Lead Soldering Temperature [1/16 inch (1.6 mm) from case, 5 sec. with soldering |
| iron] 240° C ⁽²⁾ |
| Power Dissipation (Output Transistor) |
| Power Dissipation (Input Diode) |
| Notes: |

- (1) Measured with input leads shorted together and output leads shorted together.
- (2) RMA flux is recommended. Duration can be extended to 10 sec. max. when flow soldering.
 (3) Derate linearly 2.0 mW/° C above 25° C.
 (4) Derate linearly 0.60 mW/° C above 65° C.

Types 3C92C, 3C92CHR, 3C92CTX, 3C92CTXV

Electrical Characteristics (T_A = 25° C unless otherwise noted)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITION |
|-----------------------|--------------------------------------|-----------------|-----|------------|----------|--|
| Input Diode | 9 | | | | | |
| VF | Forward Voltage | | | 1.2 1.5 | V | l _F = 2 mA l _F = 50 mA |
| VR | Reverse Voltage | 7 | | | V | I _R = 0.1 mA |
| IR | Reverse Current | | | 1 | μА | V _R = 3 V |
| CiN | Diode Capacitance | | 25 | | pF | V = 0, f = 1 MHz |
| Phototrans | sistor | | | | | T |
| V _(BR) CEO | Collector-Emitter Breakdown Voltage | 50 | | | V | I _C = 10 mA |
| V _{(BR)ECO} | Emitter-Collector Breakdown Voltage | 7 | | | V | I _C = 10 μA |
| ICEO | Collector-Emitter Leakage Current | | | 10 50 | nA nA | V _{CE} = 5 V V _{CE} = 50 V |
| Coupled | | | | | | |
| IC(ON) | On-State Collector Current | 4.0 3.0 | | _ 20 | mA mA | I _F = 10 mA, V _{CE} = 5 V I _F = 10 mA, V _{CE} = 0.4 V |
| V _{CE} (SAT) | Collector-Emitter Saturation Voltage | | | 0.4 | V | I _F = 50 mA, I _C = 10 mA |
| ton | Turn on Time | | | 9 | μs | $V_{CC} = 5 \text{ V, } I_{C} = 2 \text{ mA, } R_{L} = 100 \Omega$ |
| t _{off} | Turn off Time | | | 6 | μs | |
| C _{IO} | Input-to-Output Capacitance | | 2 | 2.5 | pF | f = 1 MHz |
| Rio | Isolation Resistance | 10 ⁹ | | | Ω | $V_{IO} = +1 \text{ kV}$ |